Improving OLED performance via semiconductor dilution

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'Intrinsic' properties of OLED materials

- Refractive index n ~ 1.7
 - Limits optical outcoupling efficiency
- Glass transition temperature T_g ~ 100-120°C
 - OLED panels operate at elevated temperature
 - Thermal stability closely connected to catastrophic failure
 - Intrinsic OLED lifetime ~ exp(-E_A/kT)

What if we could change properties like these without re-engineering OLED molecules?





Most of the molecules aren't necessary



Transport is percolative, involves <5% of all molecules

Changing blend properties with Teflon AF



What happens to electrical transport?



Decreases drive voltage for up to 50% Teflon:NPD

High temperature performance



How we think it works



What's happening electrically?

- NPD hole-only diodes:
 - Suggests improved injection but degraded bulk transport
- Injection improves:
 - Interface dipole reduces hole injection barrier
 - Reduces V_{bi}

- Bulk mobility decreases
 - Reduced disorder
 - Reduced percolation



Prospects for improvement?



Questions for the community

- What if we could tailor µ and n in every transport layer of a WOLED stack?
 - What does the grand electrical & optical optimization look like?
 - What does the magic dilution molecule look like? (We don't want Teflon AF)
 - Is there economic value in displacing the cost of 'expensive' organic semiconductors?

Should dilution molecules become another standard ingredient for OLEDs? (like emitters, HTMs, ETMs, HBLs, EBLs, etc)





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